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# Semiconductor Lasers and Applications IV

Ning-Hua Zhu Jinmin Li Farzin Amzajerdian Hiroyuki Suzuki Editors

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## Contents

- vii Symposium Committees
- ix Conference Committee
- xi Fibre optic systems for gas detection principles, progress, and prospects (Plenary Paper) [7853-150]
   B. Culshaw, Univ. of Strathclyde (United Kingdom)

#### SESSION 1 NOVEL SEMICONDUCTOR LASERS

- 7844 02 Novel semiconductor lasers and integrated photonic devices (Invited Paper) [7844-01] J.-J. He, J. Jin, D. Liu, L. Jin, M. Lou, T. Yu, L. Wang, Zhejiang Univ. (China)
- High brightness InAs/GaAs quantum dot tapered laser at 1.3 µm with high temperature stability [7844-03]
   Y.-L. Cao, P. Xu, H.-M. Ji, T. Yang, L.-H. Chen, Institute of Semiconductors (China)
- 7844 05 Beam-shaping of laser diode stack for uniform illumination by cylindrical micro-lenses
   [7844-04]
   W. ShangGuan, H. Yan, Y. Jiang, X. Zhang, C. Yang, Zhejiang Univ. (China)
- 7844 09 **Experimental demonstration of a widely tunable two-section DFB laser** [7844-08] Y. Wang, M. Li, J.-J. He, Zhejiang Univ. (China)

#### SESSION 2 SEMICONDUCTOR LASER APPLICATIONS

- 7844 0D Optical fiber sensors for landslide monitoring (Invited Paper) [7844-12]
   Y. Liu, Z. Dai, X. Zhang, Z. Peng, J. Li, Z. Ou, Y. Liu, Univ. of Electronic Science and Technology of China (China)
- Suppression of time delay signatures of chaotic output in mutually delay-coupled semiconductor lasers [7844-13]
   J.-G. Wu, Southwest Univ. (China); Z.-M. Wu, Southwest Univ. (China) and Southeast Univ. (China); J.-T. Shen, L. Ding, N.-Y. Li, Southwest Univ. (China); G.-Q. Xia, Southwest Univ. (China) and Southeast Univ. (China)
- Power equalization using nonlinear polarization rotation in a single semiconductor optical amplifier (Invited Paper) [7844-16]
   S. J. Zhang, Y. L. Zhang, K. Zhang, S. Liu, Y. Z. Liu, Y. Liu, Univ. of Electronic Science and Technology of China (China)
- A novel optical heterodyne approach for measuring frequency responses of photodetectors [7844-17]
   Q. Yan, Y. Huang, X. Duan, D. He, H. Huang, X. Zhang, Q. Wang, X. Ren, Beijing Univ. of Posts and Telecommunications (China)

#### SESSION 3 SIMULATION, CHARACTERISTICS, AND PACKAGING

- Phase estimation in coherent communication systems with semiconductor laser noises (Invited Paper) [7844-19]
   C. Yu, National Univ. of Singapore (Singapore) and A\*STAR Institute for Infocomm Research (Singapore); P. Y. Kam, S. Zhang, A\*STAR Institute for Infocomm Research (Singapore); J. Chen, Nanjing Univ. of Posts and Telecommunications (China)
- Theoretical analysis of emission characteristics of second-order distributed feedback semiconductor lasers [7844-20]
   L. Qin, Changchun Institute of Optics, Fine Mechanics and Physics (China); S. Ye, Y. Hu, N. Zhang, Changchun Institute of Optics, Fine Mechanics and Physics (China) and Graduate Univ. of Chinese Academy of Sciences (China); Y. Ning, Y. Liu, L. Wang, Changchun Institute of Optics, Fine Mechanics and Physics (China)
- 7844 0M Intracavity second harmonic generation characteristics of semiconductor disk laser [7844-21]

Z. Li, Y. Song, P. Zhang, X. Zhang, Beijing Univ. of Technology (China)

- 7844 0N **Optical bistability in InP/InAlGaAs multi-quantum-well semiconductor ring lasers** [7844-22] Y. Chen, L. Mao, W. Guo, S. Zhang, S. Xie, J. Yu, X. Yu, Tianjin Univ. (China); X. Li, L. Qi, China Electronics Technology Group Corp. (China); X. Gu, Tianjin Polytechnic Univ. (China)
- 7844 00 **Electromagnetic optimization of high-speed TO laser modules (Invited Paper)** [7844-23] W. Han, P. O'Brien, M. Rensing, H. Yang, Tyndall National Institute (Ireland); F. H. Peters, Tyndall National Institute (Ireland) and Univ. College Cork (Ireland)
- High-speed analog DFB laser module operated in direct modulation for Ku-band (Invited Paper) [7844-24]
   Y. Liu, J. W. Man, W. Han, X. Wang, H. Q. Yuan, H. L. Zhu, L. Xie, N. H. Zhu, Institute of Semiconductors (China)
- 7844 0Q Experimental observations of bistable characteristics of an optically injected semiconductor laser biased nearby the threshold current [7844-25]
   X.-D. Lin, Southwest Univ. (China); Z.-M. Wu, Southwest Univ. (China) and Southeast Univ. (China); L. Wang, X.-X. Ping, Southwest Univ. (China); G.-Q. Xia, Southwest Univ. (China) and Southeast Univ. (China)
- 7844 OR Influence of asymmetrical bias currents on chaos synchronization performance of mutually coupled semiconductor lasers [7844-26]
   T. Deng, G.-Q. Xia, Y. He, Y.-Y. Liu, Southwest Univ. (China); Z.-M. Wu, Southwest Univ. (China) and Southeast Univ. (China)
- 7844 0S Analysis of strain energy in nanowire heterostructures with component gradient buffer section [7844-27]
   Y. Liu, X. Ye, H. Huang, J. Guo, X. Ren, Y. Huang, Beijing Univ. of Posts and Telecommunications (China)
- 7844 0T **Experimental study of laser dicing sapphire substrate by green DPSS laser** [7844-28] X. Xie, F. Huang, X. Wei, W. Hu, Q. Ren, Guangdong Univ. of Technology (China)

### POSTER SESSION

7844 OW	<b>A common aperture active imaging system</b> [7844-31] N. Zhang, Y. Tang, L. Zhang, G. Huang, Beijing Institute of Technology (China)
7844 OY	Self-mixing interference effect of VCSEL and the application on microdisplacement measurement [7844-33] H. Hao, M. Wang, D. Guo, W. Xia, Nanjing Normal Univ. (China)
7844 OZ	Distributed Bragg reflector mirror with a double-wavelength reflection: design and calculation [7844-34] C. Yan, L. Xu, Y. Feng, Y. Hao, Y. Deng, Y. Zhao, J. Zhong, C. Tian, X. Jia, Changchun Univ. of Science and Technology (China)
7844 10	A simple wavelength-locking scheme of a tunable three-electrode distributed Bragg reflector laser for multiple ITU channel application in C band [7844-35] N. Ye, Y. Liu, LJ. Zhao, Institute of Semiconductors (China)
7844 11	<b>Optical influence of different standard illuminants on green nephrite's color From Manasi</b> [7844-36] H. Du, Y. Guo, China Univ. of Geosciences (China)
7844 12	<b>The contribution of Cu<sup>2+</sup>, Fe<sup>2+</sup>, F <sup>3+</sup> to bluish green color of HuBei turquoise</b> [7844-37] Y. Guo, L. Jin, China Univ. of Geosciences (China); H. Sun, China Building Material Test & Certification Ctr. (China)
7844 13	<b>Lifetime estimation of high power lasers</b> [7844-38] G. Lu, Y. Huang, Y. En, Science and Technology on Reliability Physics and Application of Electronic Component Lab. (China)
7844 16	An InP-based wide gain spectrum asymmetric quantum wells for large scale optoelectronic monolithic integration [7844-41] H. Xie, Z. Lu, P. Shen, C. Ding, L. Chen, W. Zhang, Beijing Univ. of Technology (China)
7844 17	<b>A special sampling technology for sampled grating laser</b> [7844-42] Y. Zhou, Nanjing Univ. (China) and Changzhou Institute of Technology (China); Y. Shi, S. Li, X. Chen, Nanjing Univ. (China)
7844 18	Multiple phase shifts DFB semiconductor laser based on reconstruction equivalent chirp technology [7844-43] Y. Shi, S. Li, L. Lu, X. Chen, Nanjing Univ. (China)
7844 19	<b>Hydrogen and argon plasma passivation technology in GaAs/AlGaAs LD cavity surfaces</b> [7844-44] C. Liu, C. Wang, Y. Yao, Jilin Normal Univ. (China)
7844 1 A	<b>Collimated the laser diode beam by the focus lens</b> [7844-45] Q. Xu, J. Li, W. Zhang, Xidian Univ. (China)

#### 7844 1B Optimal design and experimental realization of DBR-metal microcavity organic lasers [7844-46]

X. Zhao, Xi'an Jiaotong Univ. (China) and Xi'an Research Institute of Hi-Tech (China); Z. Wu, S. Liang, X. Hou, Xi'an Jiaotong Univ. (China)

- 7844 1C Demonstrations of beam quality of semiconductor lasers [7844-47] C. Cao, X. Zeng, Y. An, Xidian Univ. (China)
- 7844 1E Optimization of low threshold currents in proton implanted vertical cavity surface emitting lasers [7844-49]

H.-D. Zhao, M. Sun, Q. Liu, W. Wang, H.-L. Liu, W.-C. Li, Hebei Univ. of Technology (China)

7844 1F Frequency stabilized system of the reference laser diode for space-borne Fourier transform spectrometer [7844-50]

X. Jin, Z. Dai, R. Chen, D. Li, X. Sun, Shanghai Institute of Technical Physics (China)

7844 1G The theoretical research of the carriers distribution in the semiconductor quantum dot [7844-51]

C. Zhao, M. Zhao, Y. Wang, Beijing Institute of Petrochemical Technology (China); Y. Cao, Beijing Institute of Petrochemical Technology (China) and Beijing Univ. of Chemical Technology (China); A. J. Lv, X. L. Liu, G. J. Xing, Beijing Institute of Petrochemical Technology (China)

7844 1H High-power, mode-locking, external-cavity feedback diode-pumped laser based on SHG in PPKTP [7844-52]

W. Li, Hebei Univ. of Technology (China) and Qinhuangdao College of Profession Technology (China); Z. Liu, Yanshan Univ. (China); H. Zhao, Hebei Univ. of Technology (China); Z. Li, Yanshan Univ. (China)

Author Index

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